# **Fast Rectifiers**

# RS1A - RS1M

### Features

- Glass–Passivated Junction
- For Surface Mounted Applications
- Built-in Strain Relief, Ideal for Automated Placement
- UL Certified: Certificate # E326243
- These Devices are Pb-Free and are RoHS Compliant



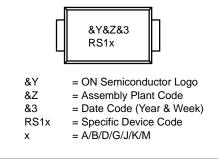
# **ON Semiconductor®**

www.onsemi.com



CASE 403AE

#### MARKING DIAGRAM



#### **ORDERING INFORMATION**

Part Number	Marking	Package	Shipping <sup>†</sup>
RS1A	RS1A	SMA (Dia Face)	7500 / Tape & Reel
RS1B	RS1B	(Pb-Free)	
RS1D	RS1D		
RS1G	RS1G		
RS1J	RS1J		
RS1K	RS1K		
RS1M	RS1M		

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# RS1A – RS1M

## SPECIFICATIONS

#### **ABSOLUTE MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

		Value							
Symbol	Parameter	RS1A	RS1B	RS1D	RS1G	RS1J	RS1K	RS1M	Units
V <sub>RRM</sub>	Maximum Repetitive Reverse Voltage	50	50 100 200 400 600 800 1000				1000	V	
I <sub>F(AV)</sub>	Average Rectified Forward Current at $T_A = 100^{\circ}C$	1.0							A
I <sub>FSM</sub>	Non–Repetitive Peak Forward Surge Current: 8.3 ms Single Half–Sine Wave	30				A			
TJ	Operating Junction Temperature	-55 to +150					°C		
T <sub>STG</sub>	Storage Temperature Range	-55 to +150					°C		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### **THERMAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Value	Unit
PD	Power Dissipation	1.19	W
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance (Note 1)	105	°C/W
$R_{\thetaJL}$	Junction-to-Lead Thermal Resistance (Note 1)	32	°C/W

1. Device mounted on FR-4 PCB 0.013 mm.

# **ELECTRICAL CHARACTERISTICS** (Values are at $T_A = 25^{\circ}C$ unless otherwise noted)

		Test	Value							
Symbol	Parameter	Conditions	RS1A	RS1B	RS1D	RS1G	RS1J	RS1K	RS1M	Unit
VF	Forward Voltage	I <sub>F</sub> = 1.0 A	1.3							V
t <sub>rr</sub>	Reverse Recovery Time	$I_{\rm F} = 0.5 \text{ A},$ $I_{\rm R} = 1.0 \text{ A},$ $I_{\rm rr} = 0.25 \text{ A}$	150				250	500		ns
I <sub>R</sub>	Reverse Current at Rated	T <sub>A</sub> = 25°C	5.0						μΑ	
	V <sub>R</sub>	T <sub>A</sub> = 125°C	50							
CT	Total Capacitance	V <sub>R</sub> = 4.0 V, f = 1.0 MHz	10						pF	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# RS1A – RS1M

## **TYPICAL PERFORMANCE CHARACTERISTICS**

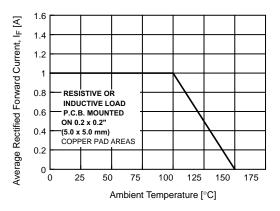


Figure 1. Forward Current Derating Curve

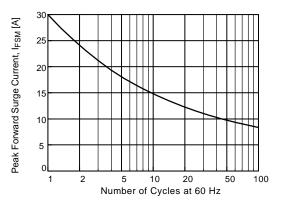


Figure 2. Non–Repetitive Surge Current

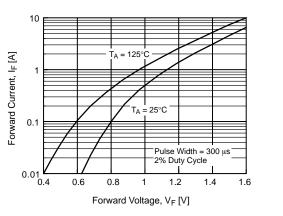
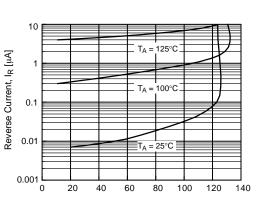


Figure 3. Forward Voltage Characteristics



Percent of Rated Peak Reverse Voltage [%]

Figure 4. Reverse Current vs. Reverse Voltage

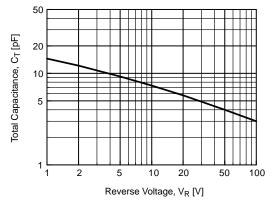


Figure 5. Total Capacitance



SMA CASE 403AE ISSUE O DATE 31 AUG 2016 5.60  $\oplus$ 0.13 (M) В С В Α B 4.80 2.65 2.95 1.65 1.75 ́Β` 2.50 1.20 4.30 4.75 ΈB A 4.00 LAND PATTERN RECOMMENDATION **TOP VIEW** 2.50 MAX 2.20 NOTES: 1.90 A. EXCEPT WHERE NOTED, CONFORMS TO JEDEC DO214 VARIATION AC. 0.30 ∕B` DOES NOT COMPLY JEDEC STANDARD 0.203 Β 0.05 VALUE. 0.050 С C. ALL DIMENSIONS ARE IN MILLIMETERS. 2.05 D. DIMENSIONS ARE EXCLUSIVE OF **⊕**|0.13 (M) С В Α 1.95 BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS. SIDE VIEW Ε. DIMENSIONS AND TOLERANCE AS PER ASME Y14.5-2009. E. LAND PATTERN STD. DIOM5025X231M **8**° 0 R0.15 4X GAGE PLANE 0.45 0.41 0.15 1.52 **8** ° 0.75 **0** ° **DETAIL A** SCALE 20:1 Electronic versions are uncontrolled except when accessed directly from the Document Repository. DOCUMENT NUMBER: 98AON13440G Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red. PAGE 1 OF 1 **DESCRIPTION:** SMA

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